# 2SD2176

NPN Epitaxial Planar Silicon Transistor

## Motor Driver Applications

### Features

- · Darlington connection
- $\cdot$  On-chip zener diode of  $60\pm10 \text{V}$  between collector and base

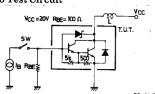
No.3196

- · High inductive load handling capability
- · Small-sized package

Absolute Maximum Ratings at Ta=25°C					unit	
Collector to Base Voltage	$V_{CBO}$	On-chip zener diode $(60 \pm 10 \text{V})$		50	V	
Collector to Emitter Voltage	$V_{CEO}$	"		50	V	
Emitter to Base Voltage	$V_{EBO}$			6	V	
Collector Current	$I_{\mathbf{C}}$			1.2	Α	
Collector Current(Pulse)	$I_{CP}$			2.5	Α	
Base Current	$I_B$			0.2	Α	
Collector Dissipation	P <sub>C</sub> Mo	unted on ceramic board (250mm <sup>2</sup>	$\times 0.8$ mm)	1.3	W	
Junction Temperature	Тj			150	$^{\circ}\mathrm{C}$	
Storage Temperature	Tstg		- 55 to	+150	°C	
Electrical Characteristics at Ta = 25°C			min	typ	max	unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 40V, I_E = 0$		₹J P	10	μA
Emitter Cutoff Current	IEBO	$V_{EB} = 5V_{IC} = 0$			2	mA
DC Current Gain	hFE	$V_{CE} = 3V_1I_C = 500 \text{mA}$	1000		20000	
C-E Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C} = 500 \text{mA}, I_{B} = 1 \text{mA}$		1.0	1.5	V
B-E Saturation Voltage	V <sub>BE(sat)</sub>			1.5	2	v
C-B Breakdown Voltage	V <sub>(BR)CBC</sub>		50	-10	70	v
C-E Breakdown Voltage	V <sub>(BR)CEC</sub>		50		70	v
Inductive Load Handling	Es/b	$L = 30 \text{mH}, R_{BE} = 100 \Omega$	15		,	mJ
Capability		. 55				3420

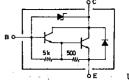
Marking: DQ

### Es/b Test Circuit

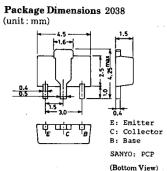


Unit (Resistance :  $\Omega$ )

## **Electrical Connection**

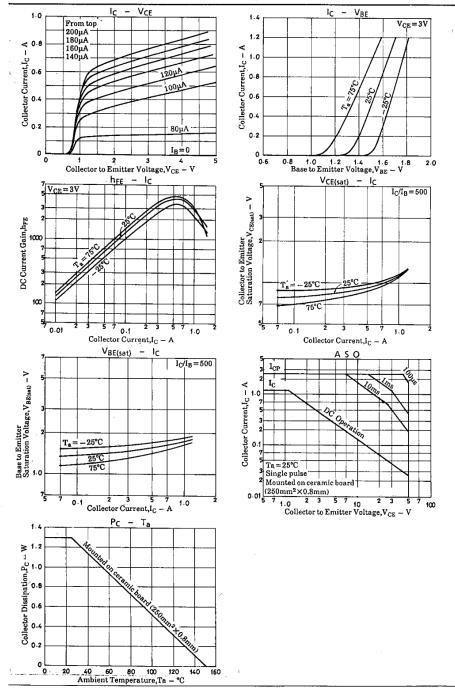


Unit (Resistance :  $\Omega$ )



SANYO Electric Co., Ltd. Semiconductor Business Headquarters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

7149MO,TS No.3196-1/3



- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:

  Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all olaims and lifigation and all damages, cost and expenses associated with such use:

  Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guarant-eed for volume production, SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.